



## UTT80N05

Preliminary

Power MOSFET

### 80A, 50V N-CHANNEL POWER MOSFET

#### DESCRIPTION

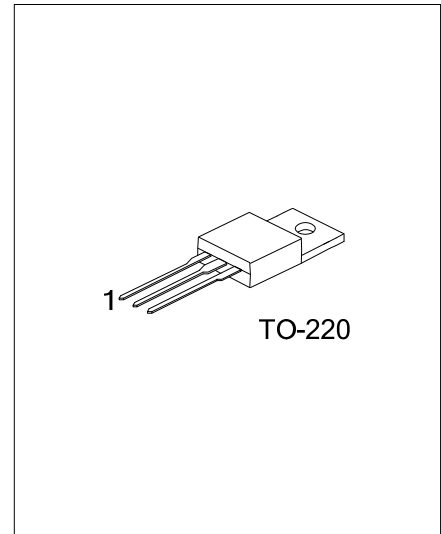
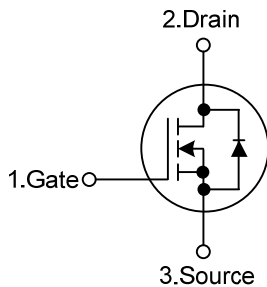
The UTC **UTT80N05** is an N-channel enhancement mode power MOSFET using UTC's advanced technology to provide customers with a minimum on-state resistance, superior switching performance and low gate charge.

The UTC **UTT80N05** is suitable for switching regulators, DC linear mode control, automotive systems, solenoid & motor control, etc.

#### FEATURES

- \*  $R_{DS(ON)} = 5.1m\Omega @ V_{GS}=10V, I_D=80A$
- \* High switching speed

#### SYMBOL



#### ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
UTT80N05L-TA3-T	UTT80N05G-TA3-T	TO-220	G	D	S	Tube

Note: Pin Assignment: G: Gate D: Drain S: Source

UTT80N05L-TA3-T 	(1) Packing Type (2) Package Type (3) Lead Free	(1) T: Tube (2) TA3: TO-220 (3) G: Halogen Free, L: Lead Free
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■ ABSOLUTE MAXIMUM RATINGS ( $T_J=25^{\circ}\text{C}$ , unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage (Note 2)		$V_{DSS}$	50	V
Gate-Source Voltage		$V_{GSS}$	$\pm 20$	V
Drain Current	Continuous ( $T_C < 135^{\circ}\text{C}$ , $V_{GS}=10\text{V}$ )	$I_D$	80	A
	Pulsed	$I_{DM}$	320	A
Single Pulsed Avalanche Energy (Note 3)		$E_{AS}$	860	mJ
Power Dissipation		$P_D$	312	W
Derate Above $25^{\circ}\text{C}$			2.5	W/ $^{\circ}\text{C}$
Junction Temperature		$T_J$	+150	$^{\circ}\text{C}$
Storage Temperature		$T_{STG}$	-55~+150	$^{\circ}\text{C}$

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Starting  $T_J=25\sim 150^{\circ}\text{C}$

3. Starting  $T_J=25^{\circ}\text{C}$ ,  $L = 0.42\text{mH}$ ,  $I_{AS} = 64\text{A}$

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	$\theta_{JA}$	62	$^{\circ}\text{C/W}$
Junction to Case	$\theta_{JC}$	0.4	$^{\circ}\text{C/W}$

■ ELECTRICAL CHARACTERISTICS ( $T_J=25^{\circ}\text{C}$ , unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>OFF CHARACTERISTICS</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$I_D=250\mu\text{A}$ , $V_{GS}=0\text{V}$	50			V
Drain-Source Leakage Current	$I_{DSS}$	$V_{DS}=50\text{V}$ , $V_{GS}=0\text{V}$			1	$\mu\text{A}$
Gate-Source Leakage Current	Forward	$I_{GSS}$			+100	nA
					Reverse	-100
<b>ON CHARACTERISTICS</b>						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS}=V_{GS}$ , $I_D=250\mu\text{A}$	2	2.8	4	V
Static Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS}=10\text{V}$ , $I_D=80\text{A}$		5.1	7	m $\Omega$
<b>DYNAMIC PARAMETERS</b>						
Input Capacitance	$C_{ISS}$	$V_{GS}=0\text{V}$ , $V_{DS}=25\text{V}$ , $f=1.0\text{MHz}$		3565		pF
Output Capacitance	$C_{OSS}$			1310		pF
Reverse Transfer Capacitance	$C_{RSS}$			395		pF
<b>SWITCHING PARAMETERS</b>						
Total Gate Charge at 20V	$Q_G$	$V_{DD}=30\text{V}$ , $I_D=80\text{A}$ , $R_L=0.4\Omega$		207	269	nC
Gate to Source Charge	$Q_{GS}$			17.2		nC
Gate to Drain Charge	$Q_{GD}$			52		nC
Turn-ON Delay Time	$t_{D(ON)}$	$V_{DD}=30\text{V}$ , $I_D=80\text{A}$ , $R_L=0.4\Omega$ , $V_{GS}=10\text{V}$ , $R_{GS}=2.5\Omega$		12		ns
Rise Time	$t_R$			34		ns
Turn-OFF Delay Time	$t_{D(OFF)}$			37		ns
Fall-Time	$t_F$			23		ns
<b>SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS</b>						
Drain-Source Diode Forward Voltage	$V_{SD}$	$I_{SD}=80\text{A}$		0.9	1.25	V

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